TOSHIBA Field Effect Transistor Silicon N Channel Junction Type

2SK30ATM

Low Noise Pre-Amplifier, Tone Control Amplifier and DC-AC High Input Impedance Amplifier Circuit Applications

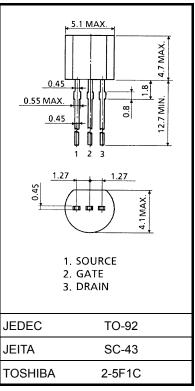
- High breakdown voltage: $V_{GDS} = -50 \text{ V}$
- High input impedance: $I_{GSS} = -1 \text{ nA (max) (V}_{GS} = -30 \text{ V)}$
- Low noise: NF = 0.5dB (typ.)

 $(V_{DS} = 15 \text{ V}, V_{GS} = 0, R_{G} = 100 \text{ k}\Omega, f = 120 \text{ Hz})$

Maximum Ratings (Ta = 25°C)

| Characteristics | Symbol | Rating | Unit |
|---------------------------|------------------|---------|------|
| Gate-drain voltage | V_{GDS} | -50 | V |
| Gate current | IG | 10 | mA |
| Drain power dissipation | P_{D} | 100 | mW |
| Junction temperature | Tj | 125 | °C |
| Storage temperature range | T _{stg} | -55~125 | °C |

Unit: mm

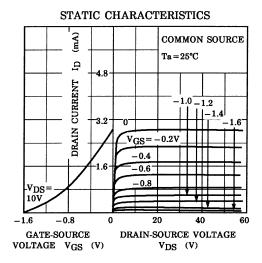


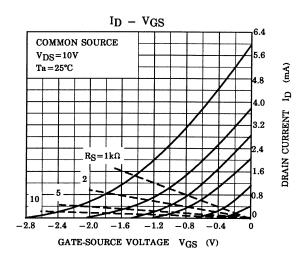
Weight: 0.21 g (typ.)

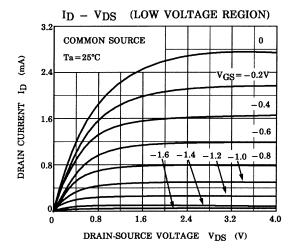
Electrical Characteristics (Ta = 25°C)

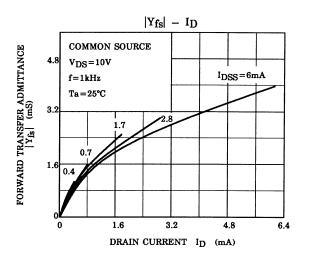
| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|------------------------------|-------------------------|--|------|------|------|------|
| Gate cut-off current | I _{GSS} | $V_{GS} = -30 \text{ V}, V_{DS} = 0$ | _ | _ | -1.0 | nA |
| Gate-drain breakdown voltage | V (BR) GDS | $V_{DS} = 0$, $I_G = -100 \mu A$ | -50 | _ | _ | V |
| Drain current | I _{DSS} (Note) | V _{DS} = 10 V, V _{GS} = 0 | 0.3 | _ | 6.5 | mA |
| Gate-source cut-off voltage | V _{GS} (OFF) | $V_{DS} = 10 \text{ V}, I_D = 0.1 \mu A$ | -0.4 | _ | -5.0 | V |
| Forward transfer admittance | Y _{fs} | $V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ kHz}$ | 1.2 | _ | _ | mS |
| Input capacitance | C _{iss} | $V_{GS} = 0, V_{DS} = 0, f = 1 \text{ MHz}$ | _ | 8.2 | _ | pF |
| Reverse transfer capacitance | C _{rss} | $V_{GD} = -10 \text{ V}, V_{DS} = 0, f = 1 \text{ MHz}$ | _ | 2.6 | _ | pF |
| Noise figure | NF | $V_{DS} = 15 \text{ V}, V_{GS} = 0$ $R_G = 100 \text{ k}\Omega, f = 120 \text{ Hz}$ | _ | 0.5 | 5.0 | dB |

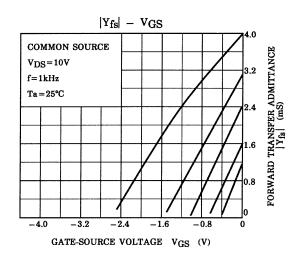
Note: IDSS classification R: 0.30~0.75, O: 0.60~1.40, Y: 1.20~3.00, GR: 2.60~6.50

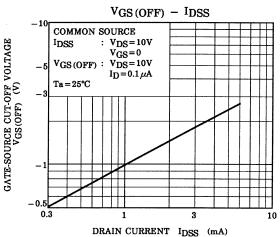




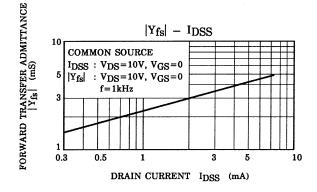


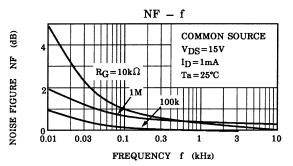


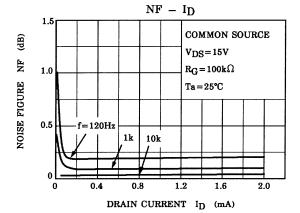


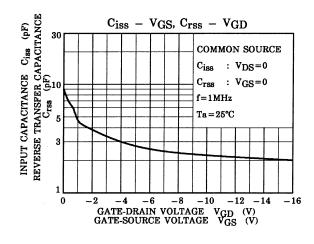


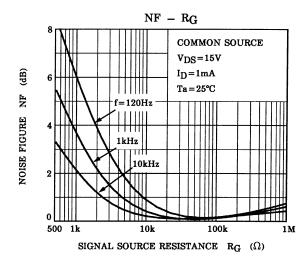
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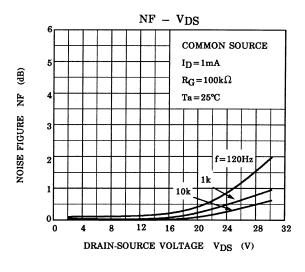


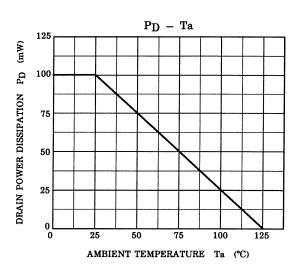












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